

Physics & Electrical Engineering Department

Fall 2018

IEEE sponsored "lunch break" LECTURE SERIES

ROOM **233** Loyola Science Center

THURSDAYS 12:00 - 12:50

Pizza & Soda 11:45 - Noon



WELCOME BACK – Summer Internships 1
WELCOME BACK – Summer Internships 2
SEMICONDUCTOR BONDING – Understanding Ultrasonic Welding
RF/MICROWAVES – My choice of an ideal career
ENTREPRENEURSHIP – For the Technically Minded
MECHANICAL ENGINEERING – Concepts, Ideas, Future
RF POWER AMPLIFICATION – Prominence of GaN Technology
PROJECT MANAGEMENT 101 – Opportunities & the Future
2019/20 ENERGY & TECHNOLOGY POLICY – US Congress

Shawn, Peter, Eileen, Dan, Jesse, Nick, Matt	Thurs, Sept 13
Shawn, Peter, Eileen, Dan, Jesse, Nick, Matt	Thurs, Sept 20
Lee Levine, Process Solutions Consulting, Inc.	Thurs, Sept 27
Mark Saffian, National Instruments	Thurs, Oct 11
Geoff Speicher, Paul Browne, UM Technologies/CTTC	Thurs, Oct 18
Barry Miles, Sr. Eng. Manager, Lockheed Martin, PA	Thurs, Oct 25
Dr. 'MD' Maktoomi, Physics/Electrical Engineering, UofS	Thurs, Nov 8
April Davis, PMI - NE Branch Manager, Keystone Chapter	Thurs, Nov 15
Russ Harrison, IEEE – USA	Thurs, Nov 29

EVERYONE WELCOME - Free Lunch 11:45 – Noon

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TRIPS to INDUSTRY

To be announced

Club Moderator:	Dr. W. Andrew Berger	Berger@Scranton.edu	(570) 941 – 4056
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The Institute for Electrical and Electronics Engineers (IEEE) is a program that provides students with the opportunity not only to participate in a campus wide event in the form of an IEEE seminar series (presentations by distinguished scientists, community business leaders, as well as our alumni and various employers/prospective job companies), but also as a time and place to pursue the club agenda, professional development and networking.

Bonding with your Semiconductor: Understanding Ultrasonic Welding

With more than 15 trillion wire bonds produced annually and volume still growing the reliability and productivity of wire bonding makes it the dominant chip interconnection method. Estimated wire bond interconnection volume exceeds 90% of market share. But that does not mean that rigorous attention to details can be ignored. New products must be fully qualified and periodic testing of the weld intermetallic is an important part of assuring high quality bonds. Process changes, materials changes and tool changes must all be tested and reliability confirmed. Long-term aging studies using accelerated high temperature storage, thermal cycling and temperature/humidity tests are not only initial qualification requirements but should be a part of any review when materials and encapsulation changes are required.

Wire bonding is a welding process where an intermetallic weld nugget (an alloy of the wire and the bond pad or substrate surface) is formed by the deformation of the ball or wire (wedge bonding). Ultrasonic energy unlocks easy slip mechanisms within the crystal lattice of the deforming materials allowing deformation at lower force and temperature than the materials would otherwise require for deformation. Deformation mixes the wire and substrate to form the initial bond. Subsequently diffusion allows the mixture to resolve into the equilibrium compounds of the phase diagram. The intermetallic compounds each have different physical properties and behavior. During the life of a wire bond it is normal for transformations to occur, where one intermetallic transforms to another because diffusion has increased (or decreased) the concentration of one of the elements. Transformations can generate large strains in the lattice structure, even resulting in bond failures at the interface between adjacent intermetallic compounds.

This talk will discuss the ultrasonic welding mechanism and its effect on wire bond reliability

Registration is required if you need parking arrangements. 1 PDH is available for IEEE members, but you must register and sign in at the meeting. Please indicate these when you register.

[Lee Levine of Process Solutions Consulting, Inc.](#)

Biography:

Lee is a consultant for Process Solutions Consulting, Inc. where he provides process engineering consultation, SEM/EDS analysis, and wire bond training. Lee's previous experience includes 20 years as Principal and Staff Metallurgical Process Engineer at Kulicke & Soffa and Distinguished Member of the Technical Staff at Agere Systems. He has been awarded 4 patents, published more than 70 technical papers, and has won both the John A. Wagnon Technical Achievement award and the Daniel C. Hughes award from the International Microelectronics and Packaging Society (IMAPs). Major innovations include copper ball bonding, loop shapes for thin, small outline packages (TSOP and TSSOP, and CSPs) and introduction of DOE and statistical techniques for understanding semiconductor assembly processes. He is an IMAPs Fellow and a senior, life member of IEEE.

Lee is a graduate of Lehigh University, Bethlehem, Pa where he earned a degree in Metallurgy and Materials Engineering.